SUP80090E



Vishay Siliconix

N-Channel 150 V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	R _{DS(on)} (Ω) MAX.	I _D (A)	Q _g (TYP.)	
150	0.0094 at V_{GS} = 10 V	128	63 nC	
150	0.0110 at V_{GS} = 7.5 V	119	03 110	

TO-220AB

Ordering Information:

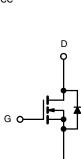
SUP80090E-GE3 (lead (Pb)-free and halogen-free)

FEATURES

- ThunderFET[®] power MOSFET
- Maximum 175 °C junction temperature
- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Power supplies:
 - Uninterruptible power supplies
 - AC/DC switch-mode power supplies
 - Lighting
- Synchronous rectification
- DC/DC converter
- Motor drive switch
- DC/AC inverter
- Solar micro inverter
- Class D audio amplifier



RoHS COMPLIANT

HALOGEN

FREE

ABSOLUTE MAXIMUM RATINGS	$(T_C = 25 \ ^{\circ}C, \text{ unless othe})$	rwise noted)			
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-Source Voltage		V _{DS}	150	V	
Gate-Source Voltage		V _{GS}	± 20	V	
Continuous Drain Current (T ₁ = 150 °C)	T _C = 25 °C	1-	128		
Continuous Drain Current $(1) = 150^{\circ}$ C)	T _C = 125 °C	I _D	74	A	
Pulsed Drain Current (t = 100 µs)		I _{DM}	240		
Avalanche Current	L = 0.1 mH	I _{AS}	60		
Single Avalanche Energy ^a		E _{AS}	180	mJ	
Maximum Bower Dissipation a	T _C = 25 °C	Р	375 ^b	w	
Maximum Power Dissipation ^a	T _C = 125 °C		125 ^b	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS			
PARAMETER	SYMBOL	LIMIT	UNIT
Junction-to-Ambient (PCB Mount) ^c	R _{thJA}	40	°C/W
Junction-to-Case (Drain)	R _{thJC}	0.4	0/11

Notes

- a. Duty cycle \leq 1 %.
- b. See SOA curve for voltage derating.

c. When mounted on 1" square PCB (FR4 material).

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PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS}=0~V,~I_D=250~\mu A$	150	-	-	V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, \ I_D = 250 \ \mu A$	2	-	5	- V	
Gate-Body Leakage	I _{GSS}	V_{DS} = 0 V, V_{GS} = ± 20 V	-	-	± 250	nA	
		$V_{DS} = 150 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	1	<u> </u>	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = 150 V, V_{GS} = 0 V, T_J = 125 $^\circ C$	-	-	100	μA 0	
		V_{DS} = 150 V, V_{GS} = 0 V, T_{J} = 175 °C	-	-	2	mA	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \geq$ 10 V, V_{GS} = 10 V	90	-	-	А	
Durin Course On Otata Desistance 3	D	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 30 \text{ A}$	-	0.0078	0.0094	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 7.5 \text{ V}, \text{ I}_{D} = 30 \text{ A}$	-	0.0087	0.0110		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 30 \text{ A}$	-	52	-	S	
Dynamic ^b							
Input Capacitance	C _{iss}		-	3425	-	pF	
Output Capacitance	C _{oss}	V _{GS} = 0 V, V _{DS} = 75 V, f = 1 MHz	-	535	-		
Reverse Transfer Capacitance	C _{rss}		-	26	-		
Total Gate Charge ^c	Qg	V _{DS} = 75 V, V _{GS} = 10 V, I _D = 60 A	-	63	95	nC	
Gate-Source Charge ^c	Q _{gs}		-	19.5	-		
Gate-Drain Charge ^c	Q _{gd}		-	20.5	-		
Gate Resistance	Rg	f = 1 MHz	1.5	3	5	Ω	
Turn-On Delay Time ^c	t _{d(on)}		-	15	30		
Rise Time ^c	tr	$V_{DD} = 75 \text{ V}, \text{ R}_{\text{I}} = 1.25 \Omega$	-	114	220	- ns	
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong$ 60 A, V_{GEN} = 10 V, R_g = 1 Ω	-	28	56		
Fall Time ^c	t _f		-	8	16		
Drain-Source Body Diode Ratings an	nd Characteri	stics ^b (T _C = 25 °C)					
Pulsed Current (t = 100 µs)	I _{SM}		-	-	240	А	
Forward Voltage ^a	V _{SD}	$I_F = 30 \text{ A}, V_{GS} = 0 \text{ V}$	-	0.73	1.2	V	
Reverse Recovery Time	t _{rr}		-	110	220	ns	
Peak Reverse Recovery Charge	I _{RM(REC)}	I _F = 30 A, di/dt = 100 A/μs	-	10	20	А	
Reverse Recovery Charge	Q _{rr}		-	0.5	1	μC	

Notes

a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$

b. Guaranteed by design, not subject to production testing.

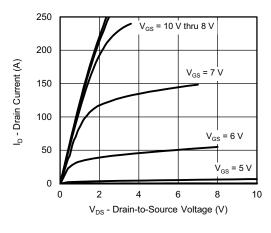
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

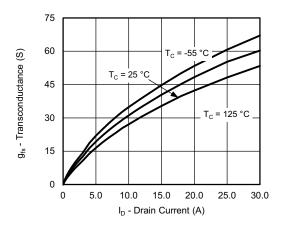
2



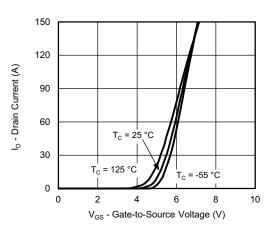
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



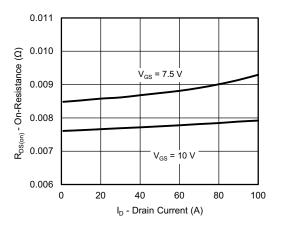
Output Characteristics



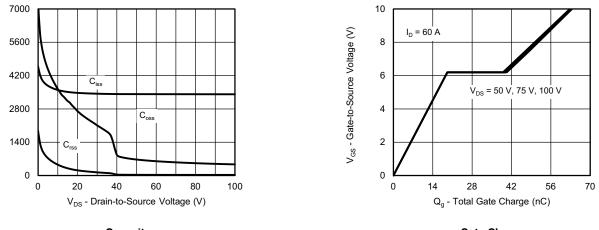
Transconductance



Transfer Characteristics



On-Resistance vs. Drain Current



Capacitance



C - Capacitance (pF)

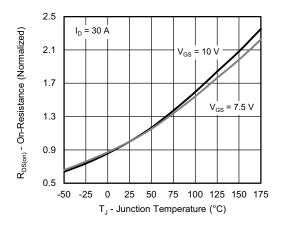
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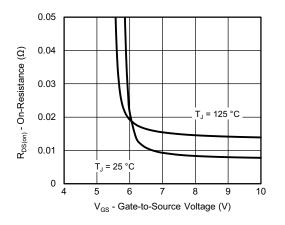
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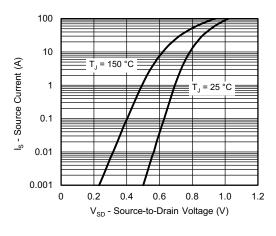
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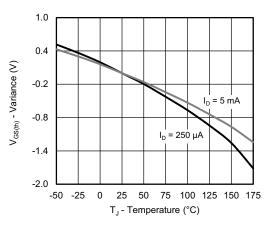
On-Resistance vs. Junction Temperature



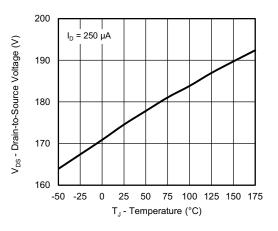
On-Resistance vs. Gate-to-Source Voltage



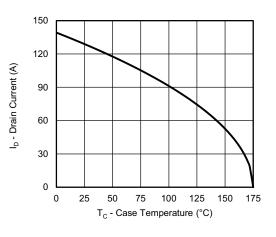
Source Drain Diode Forward Voltage



Threshold Voltage



Drain Source Breakdown vs. Junction Temperature



Current De-Rating

S16-0087-Rev. A, 25-Jan-16

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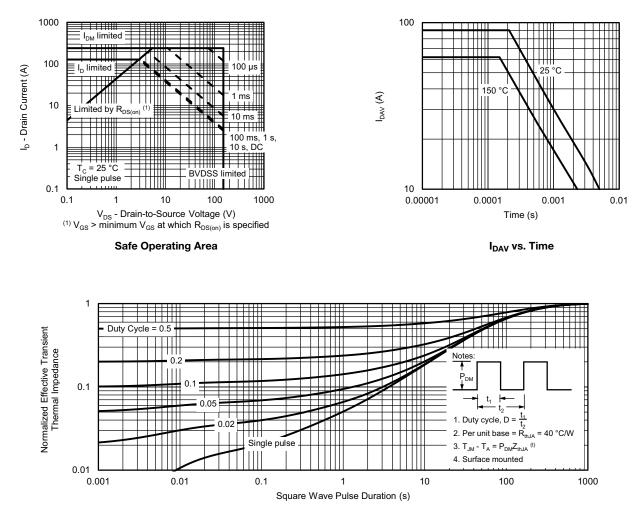
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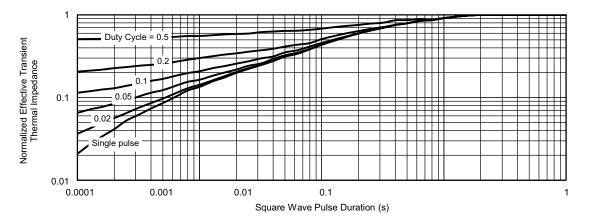
THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

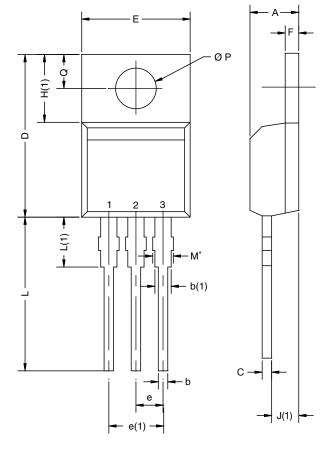
- The characteristics shown in the two graphs
- Normalized Transient Thermal Impedance Junction to Ambient (25 °C)
- Normalized Transient Thermal Impedance Junction to Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?65384.



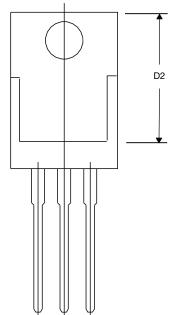
TO-220AB



	MILLIMETERS		INCHES	
DIM.	MIN.	MAX.	MIN.	MAX.
А	4.25	4.65	0.167	0.183
b	0.69	1.01	0.027	0.040
b(1)	1.20	1.73	0.047	0.068
С	0.36	0.61	0.014	0.024
D	14.85	15.49	0.585	0.610
D2	12.19	12.70	0.480	0.500
E	10.04	10.51	0.395	0.414
е	2.41	2.67	0.095	0.105
e(1)	4.88	5.28	0.192	0.208
F	1.14	1.40	0.045	0.055
H(1)	6.09	6.48	0.240	0.255
J(1)	2.41	2.92	0.095	0.115
L	13.35	14.02	0.526	0.552
L(1)	3.32	3.82	0.131	0.150
ØР	3.54	3.94	0.139	0.155
Q	2.60	3.00	0.102	0.118
	0413-Rev. P,		0.102	0.118

Note

 * M = 1.32 mm to 1.62 mm (dimension including protrusion) Heatsink hole for HVM



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